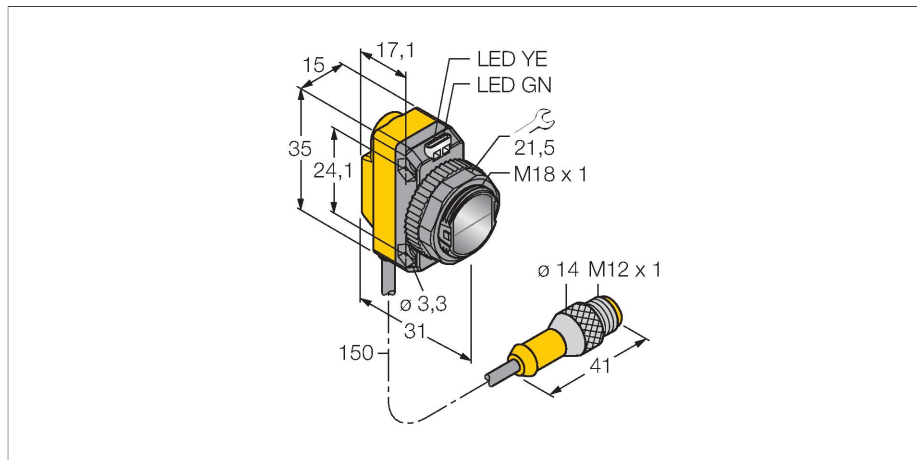


QS186EQPMA

Photoelectric Sensor – Opposed Mode Sensor (Emitter)



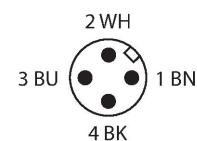
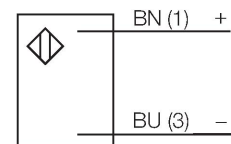
Technical data

Type	QS186EQPMA
ID	3075190
Optical data	
Function	Opposed mode sensor
Operating mode	Emitter
Light type	IR
Wavelength	940 nm
Range	0...20000 mm
Electrical data	
Operating voltage	10...30 VDC
Residual ripple	< 10 % U _{ss}
DC rated operational current	≤ 100 mA
Short-circuit protection	yes
Reverse polarity protection	yes
Readiness delay	≤ 100 ms
Mechanical data	
Design	Rectangular with thread, QS18
Dimensions	Ø 18 x 31 x 15 x 35 mm
Housing material	Plastic, ABS
Lens	plastic, Acrylic
Electrical connection	Cable with connector, M12 × 1, 0.15 m, PUR
Number of cores	4
Ambient temperature	-20...+70 °C
Protection class	IP67
Power-on indication	LED, Green
Excess gain indication	LED

Features

- Cable with male end, M12 × 1, 4-pin, PVC, 150 mm
- Protection class IP67
- LED all-round visible
- Operating voltage: 10...30 VDC

Wiring diagram



Functional principle

Opposed mode sensors consist of an emitter and receiver. They are installed opposite to each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Opposed mode sensors are the most reliable photoelectric sensors for detection of opaque targets. The excellent light/dark contrast and the high excess gain allow operation over larger distances and under difficult conditions.

Excess gain curve
Excess gain in relation to the distance (type 6EB/RB)

